

CMOS LDO Regulators for Portable Devices

1ch 150mA

CMOS LDO Regulators



BH□□SA3WGUT Series

No.11020EAT10

●Description

The BH□□SA3WGUT Series are 150 mA output CMOS regulators that deliver a highly stable output voltage with the precision of $\pm 1\%$. With the use of ROHM's original technology, the load regulation of only 2 mV, 100 mV I/O drop voltage, and the load transient of 50mV (at 1mA $\leftrightarrow$ 100mA) have been achieved. The VCSP60N1 package is extremely compact as just 0.96 mm $\times$ 0.96 mm, and the IC's enhanced protection circuits contribute to improved application safety.

●Features

- 1) High accuracy output voltage: $\pm 1\%$
- 2) I/O drop voltage: 100 mV (at 100 mA)
- 3) Load Transient ΔV_{out} : 50mV (at 1mA $\leftrightarrow$ 100mA)
- 4) Stable with ceramic capacitors (1 μ F)
- 5) Low bias current: 40 μ A
- 6) High ripple rejection ratio: 63 dB (Typ., 1 kHz)
- 7) Output voltage on/off control
- 8) Built-in overcurrent (short) and thermal shutdown circuits
- 9) Uses the VCSP60N1 WL-CSP package.

●Applications

Battery-driven portable devices, etc.

●Product Line

■150 mA BH□□SA3WGUT Series

Product name	1.8	2.8	3.0	Package
BH□□SA3WGUT	○	○	○	VCSP60N1

Model name: BH□□SA3W□
a
b

Symbol	Description	
	Output voltage specification	
a	□□	Output voltage (V)
	18	1.8 V (Typ.)
	28	2.8 V (Typ.)
	30	3.0 V (Typ.)
b	Package GUT: VCSP60N1	

●Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Applied supply voltage	V _{MAX}	-0.3 to +6.5	V
Power dissipation	P _d	530 ^{*1}	mW
Maximum junction temperature	T _{jMAX}	125	°C
Operating temperature range	T _{opr}	-40 to +85	°C
Storage temperature range	T _{stg}	-55 to +125	°C

*1: Derated at 5.3 mW/°C for temperature above T_a = 25°C, when mounted on a glass epoxy PCB (7 mm × 7 mm × 0.8 mm).

●Recommended Operating Ranges (not to exceed P_d)

Parameter	Symbol	Ratings	Unit
Power supply voltage	V _{IN}	2.2 to 5.5	V
Output current	I _{OUT}	0 to 150	mA

●Recommended Operating Conditions

Parameter	Symbol	Ratings			Unit	Conditions
		Min.	Typ.	Max.		
Input capacitor	C _{IN}	0.5 ^{*2}	1.0	—	μF	The use of ceramic capacitors is recommended.
Output capacitor	C _O	0.7 ^{*2}	1.0	—	μF	The use of ceramic capacitors is recommended.

*2: The minimum value of capacitance must be met this specifications over full operating conditions.
(ex. Temperature, DC bias, aging conditions)

● **Electrical Characteristics** (Unless otherwise specified, Ta = 25°C, VIN = VOUT + 1.0 V*6, STBY = 1.5 V, CIN = 1 μF, Co = 1 μF)

Parameter	Symbol	Limits			Unit	Conditions
		Min.	Typ.	Max.		
Output voltage 1	VOUT1	$V_{OUT} \times 0.99$	VOUT	$V_{OUT} \times 1.01$	V	IOUT = 1 mA, Ta = 25°C, VOUT ≥ 2.5V
		VOUT - 25 mV		VOUT + 25 mV		IOUT = 1mA, Ta = 25°C, VOUT < 2.5V
Output voltage 2	VOUT2	$V_{OUT} \times 0.97$	VOUT	$V_{OUT} \times 1.03$	V	IOUT = 0 to 150 mA VIN = VOUT+0.5V to 5.5V Ta = -40°C to 85°C*3,4,5
Circuit current	IGND	—	40	72	μA	IOUT = 0 mA Ta = -40°C to 85°C*4
Circuit current (STBY)	ICCST	—	—	1.0	μA	STBY = 0 V
Ripple rejection ratio	RR	50	63	—	dB	VRR = -20 dBv, fRR = 1 kHz, IOUT = 10 mA
Input output voltage difference	VSAT	—	100	150	mV	VIN = 0.98 × VOUT, IOUT = 100 mA (except BH18SA3WGUT)
Line regulation	VDLI	—	2	20	mV	IOUT = 10 mA VIN = VOUT + 0.5 V to 5.5 V*5
Load regulation1	VDLO1	—	2	30	mV	IOUT = 1 mA to 100 mA
Load regulation1	VDLO1	—	4	45	mV	IOUT = 1 mA to 150 mA
Maximum Output Current	IOMAX	150	—	—	mA	VIN = VOUT + 0.5 V*6
Limit current	ILMAX	—	400	—	mA	VO = VOUT × 0.98
Short current	ISHORT	—	50	200	mA	VO = 0 V
STBY pin current	ISTBY	0.5	1.3	3.6	μA	Ta = -40°C to 85°C*4 IOUT = 150 mA
STBY control voltage	ON	VSTBH	1.2	—	VIN	
	OFF	VSTBL	-0.2	—	0.2	

*This product is not designed for protection against radio active rays.

*3: Operating condition are limited by Pd.

*4: Typical values apply for Ta=25°C.

*5: VIN=3.0V to 5.5V for BH18SA3WGUT.

*6: VIN=3.5V for BH18SA3WGUT.

●Reference data BH18SA3WGUT (Ta=25°C unless otherwise specified.)

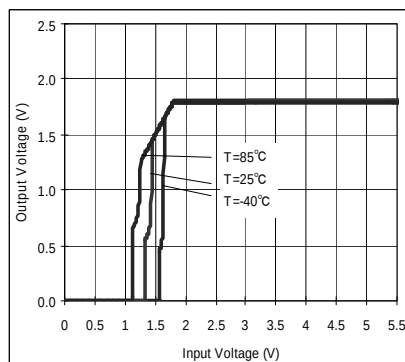


Fig.1 Output Voltage

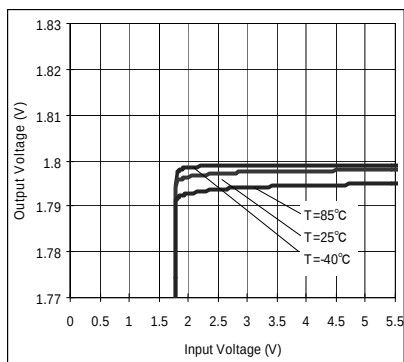


Fig.2 Line Regulation

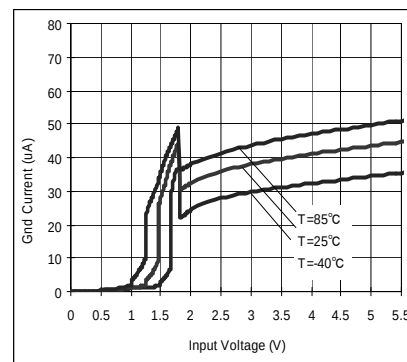


Fig.3 Circuit Current

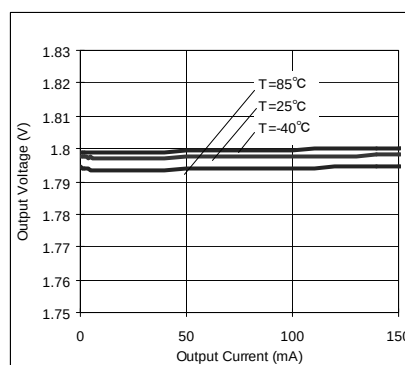


Fig.4 Load Regulation

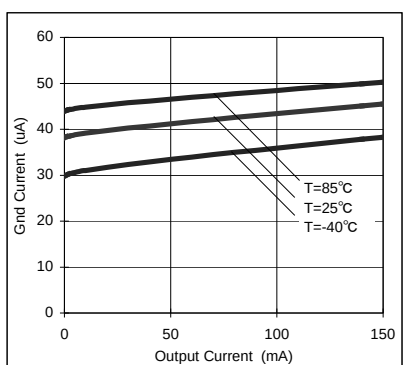


Fig.5 IOUT - IGND

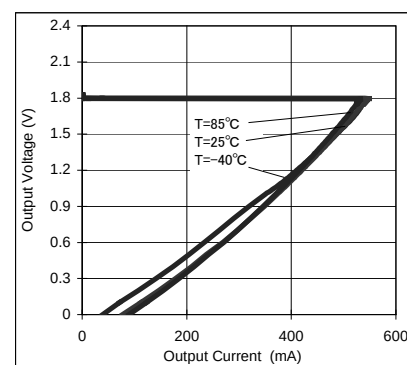


Fig.6 OCP Threshold

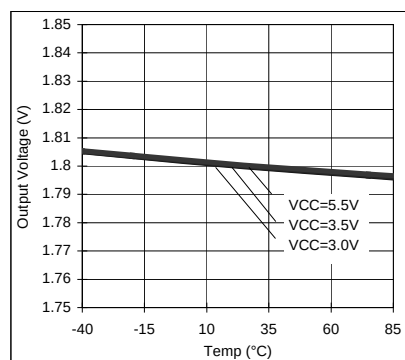


Fig.7 VOUT - Temp

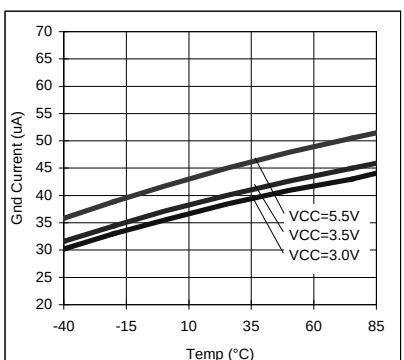


Fig.8 IGND - Temp

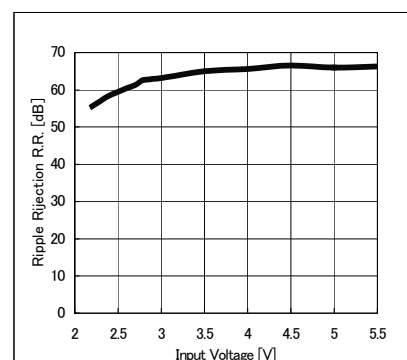


Fig.9 R.R. - VIN

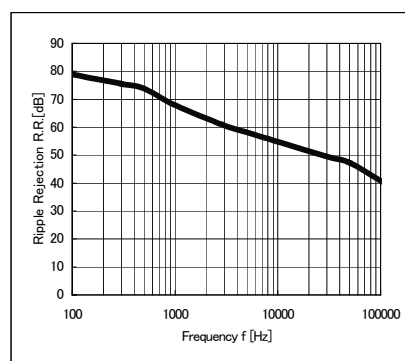


Fig.10 R.R. - Freq.

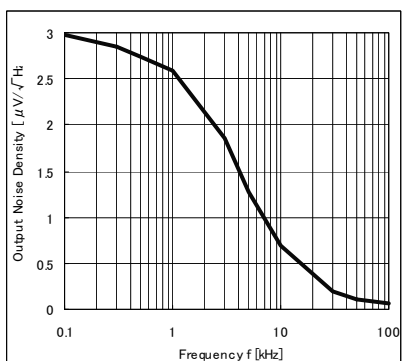


Fig.11 Noise - Freq.

●Reference data BH18SA3WGUT (Ta=25°C unless otherwise specified.)

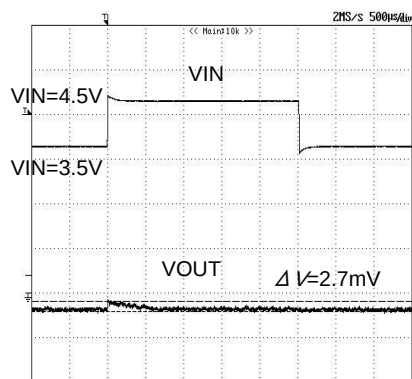


Fig.12 Transient_response
(Ta=-40°C)

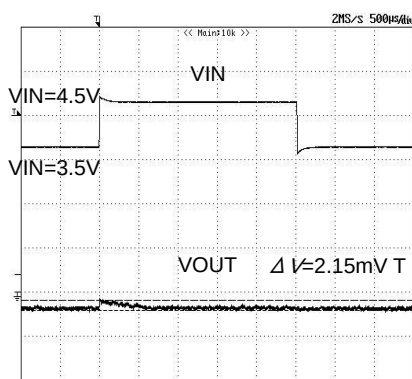


Fig.13 Transient_response
(Ta=25°C)

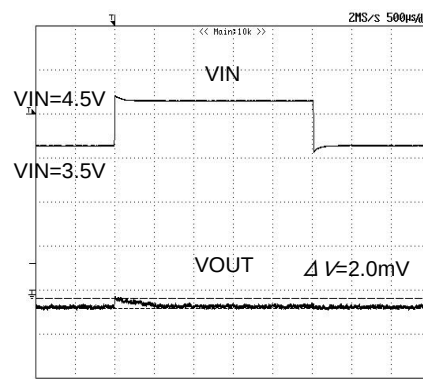


Fig.14 Transient_response
(Ta=85°C)

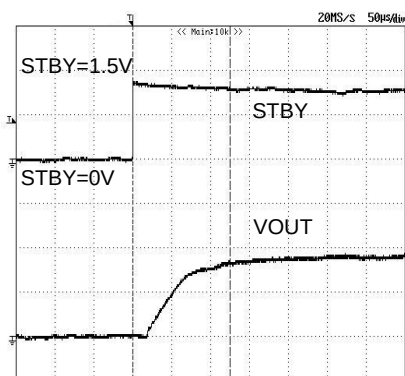


Fig.15 START_UP
(Ta=-40°C)

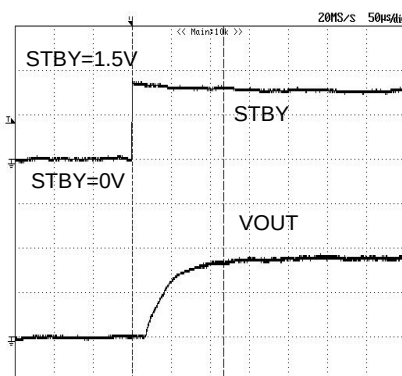


Fig.16 START_UP
(Ta=25°C)

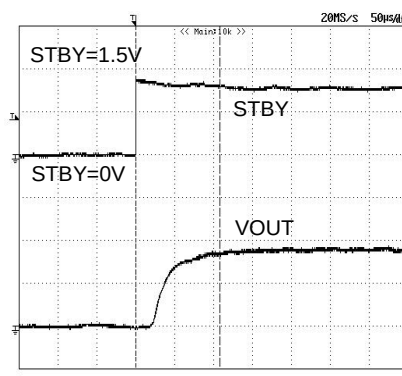


Fig.17 START_UP
(Ta=85°C)

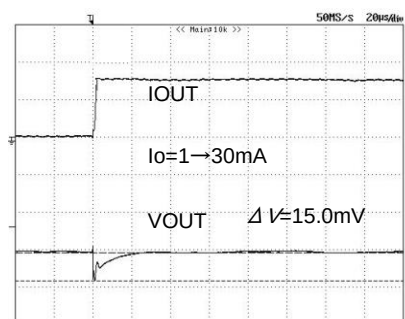


Fig.18 Load_response
(Io=1→30mA)
(Ta=-40°C)

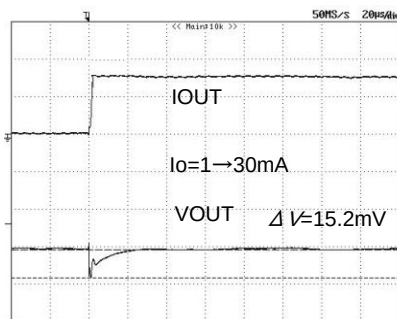


Fig.19 Load_response
(Io=1→30mA)
(Ta=25°C)

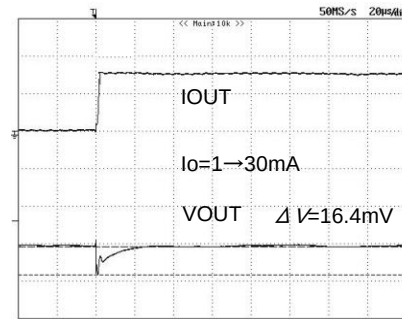


Fig.20 Load_response
(Io=1→30mA)
(Ta=85°C)

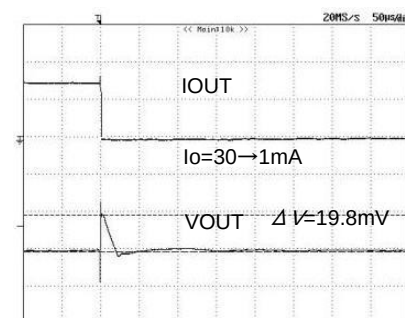


Fig.21 Load_response
(Io=30→1mA)
(Ta=-40°C)

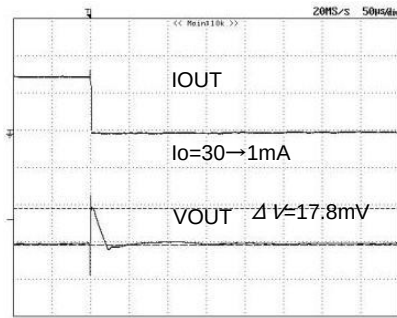


Fig.22 Load_response
(Io=30→1mA)
(Ta=25°C)

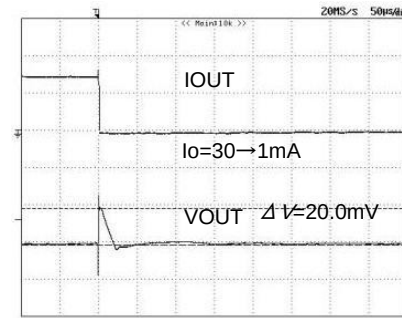


Fig.23 Load_response
(Io=30→1mA)
(Ta=85°C)

●Reference data BH28SA3WGUT (Ta=25°C unless otherwise specified.)

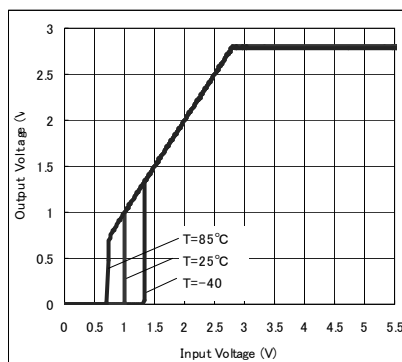


Fig.24 Output Voltage

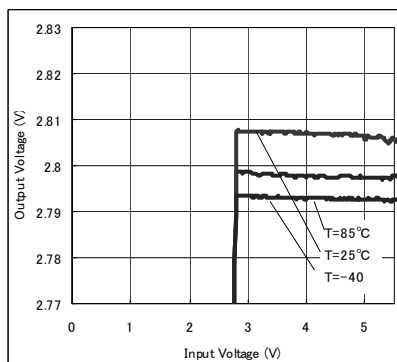


Fig.25 Line Regulation

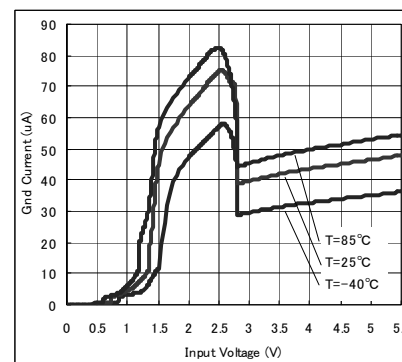


Fig.26 Circuit Current

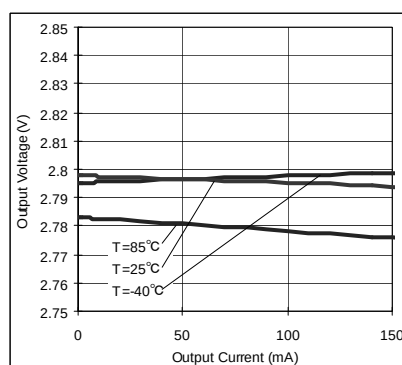


Fig.27 Load Regulation

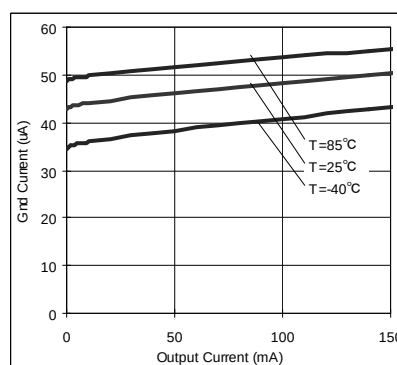


Fig.28 IOU - IGND

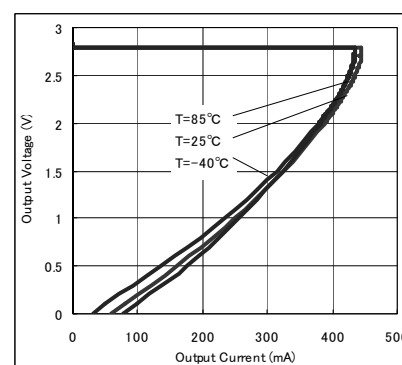


Fig.29 OCP Threshold

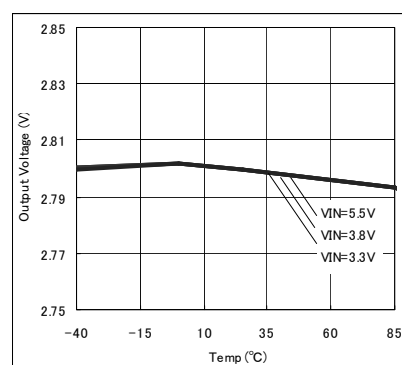


Fig.30 VOUT - Temp

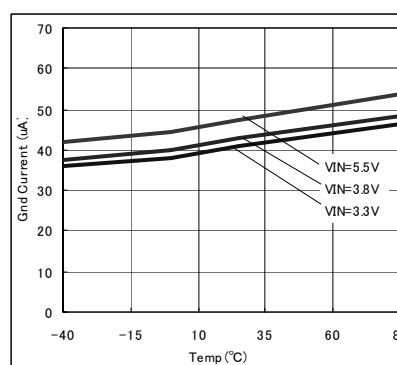


Fig.31 IGND - Temp

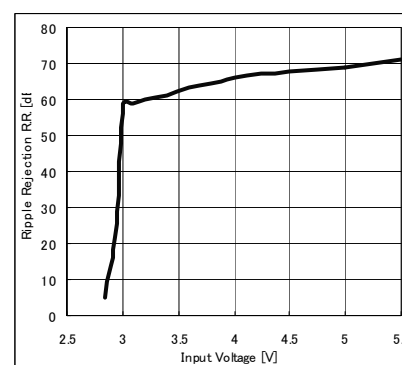


Fig.32 R.R. - VIN

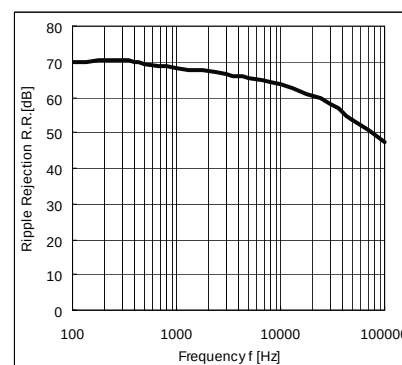


Fig.33 R.R. - Freq.

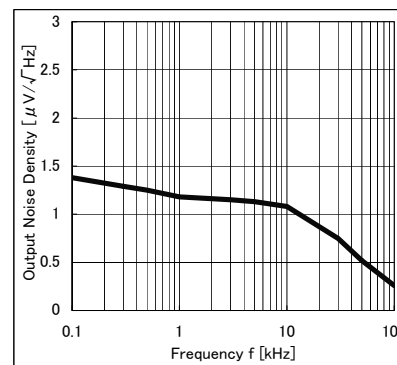


Fig.34 Noise - Freq.

●Reference data BH28SA3WGUT (Ta=25°C unless otherwise specified.)

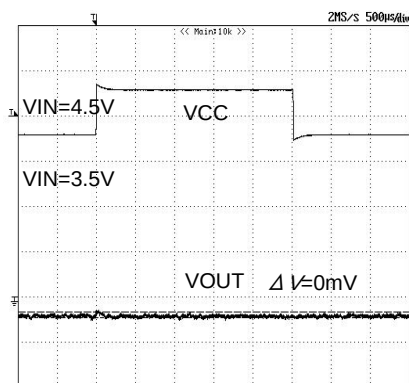


Fig.35 Transient_response
(Ta=-40°C)

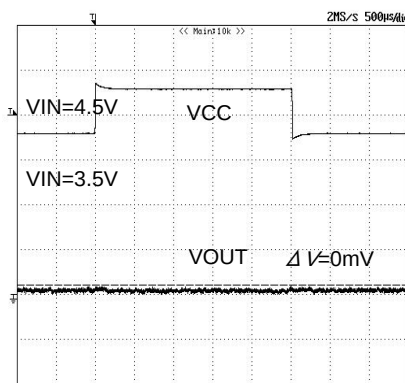


Fig.36 Transient_response
(Ta=25°C)

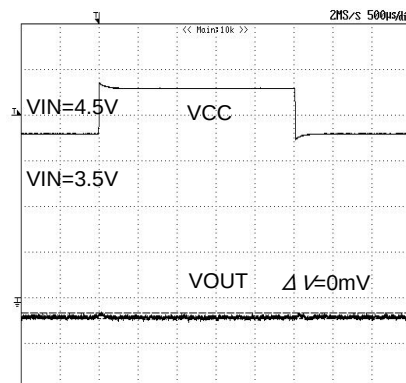


Fig.37 Transient_response
(Ta=85°C)

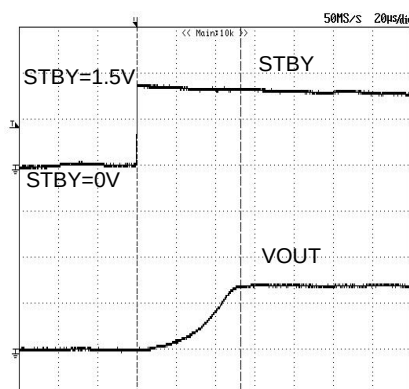


Fig.38 START_UP
(Ta=-40°C)

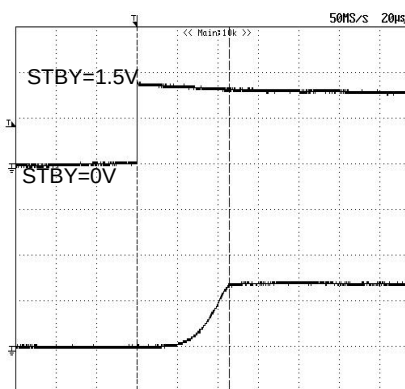


Fig.39 START_UP
(Ta=25°C)

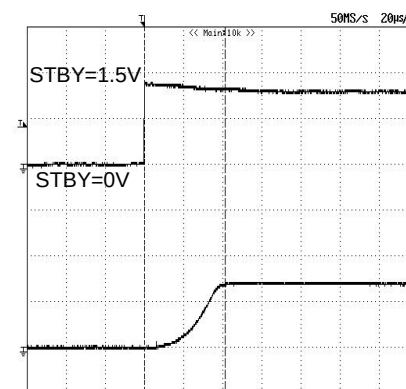


Fig.40 START_UP
(Ta=85°C)

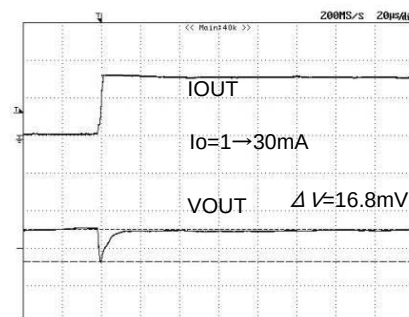


Fig.41 Load_response
(Io=1→30mA)
(Ta=-40°C)

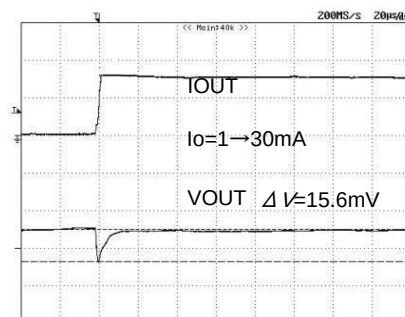


Fig.42 Load_response
(Io=1→30mA)
(Ta=25°C)

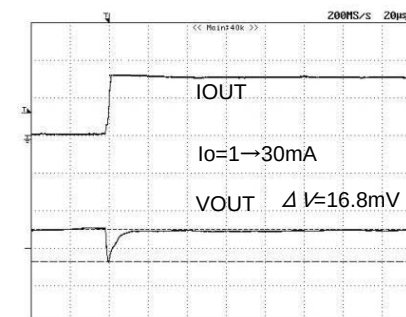


Fig.43 Load_response
(Io=1→30mA)
(Ta=85°C)

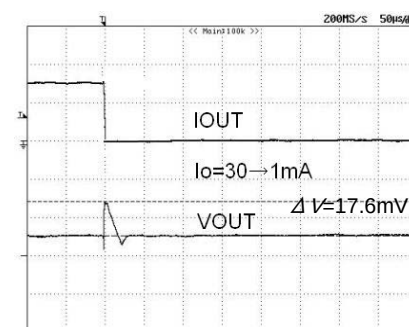


Fig.44 Load_response
(Io=30→1mA)
(Ta=-40°C)

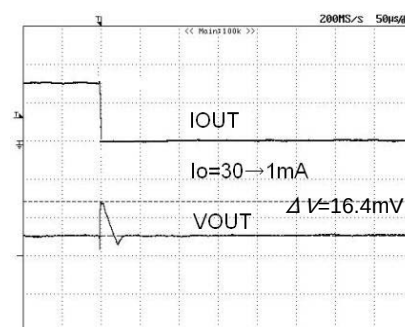


Fig.46 Load_response
(Io=30→1mA)
(Ta=25°C)

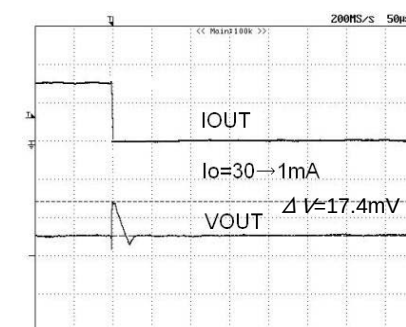


Fig.46 Load_response
(Io=30→1mA)
(Ta=85°C)

●Reference data BH30SA3WGUT (Ta=25°C unless otherwise specified.)

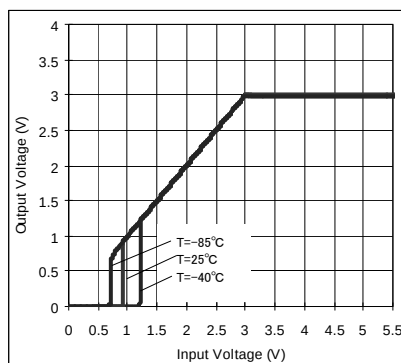


Fig.47 Output Voltage

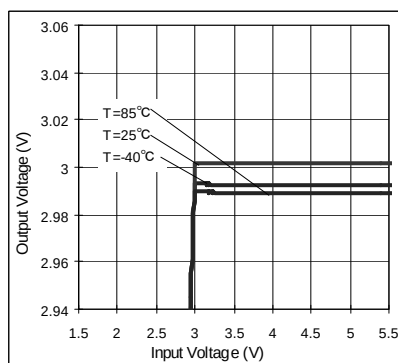


Fig.48 Line Regulation

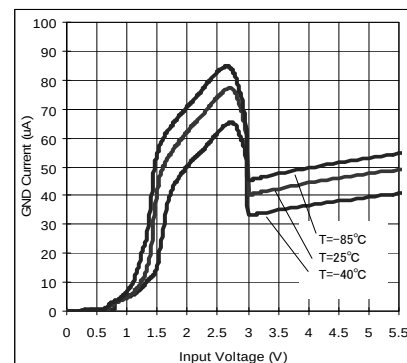


Fig.49 Circuit Current

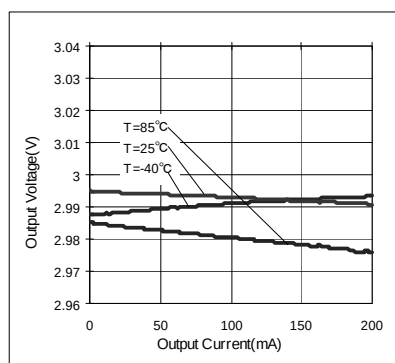


Fig.50 Load Regulation

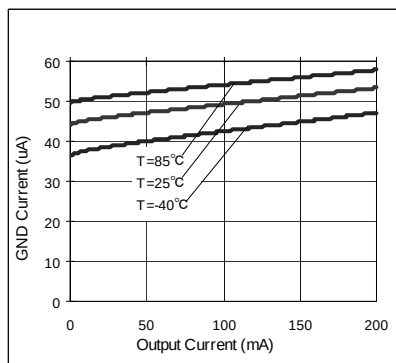


Fig.51 IOUT - IGND

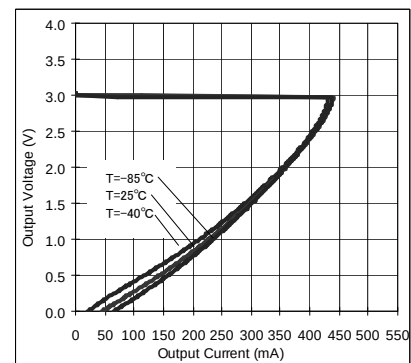


Fig.52 OCP Threshold

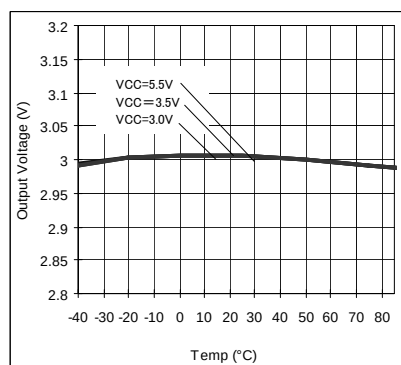


Fig.53 VOUT - Temp

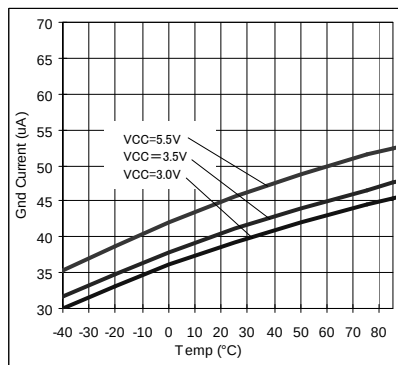


Fig.54 IGND - Temp

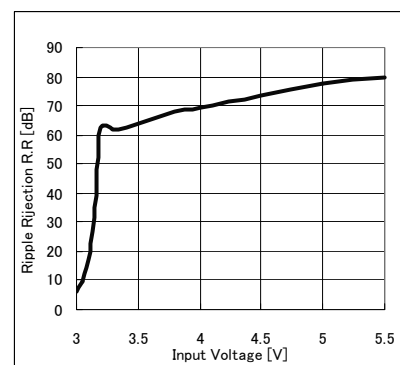


Fig.55 R.R. - VIN

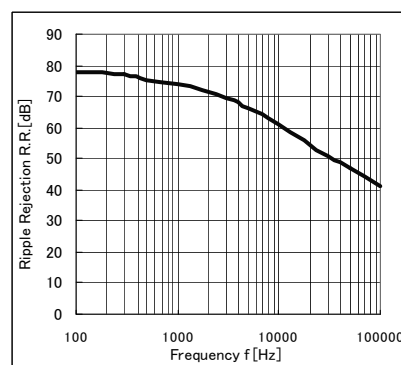


Fig.56 R.R. - Freq.

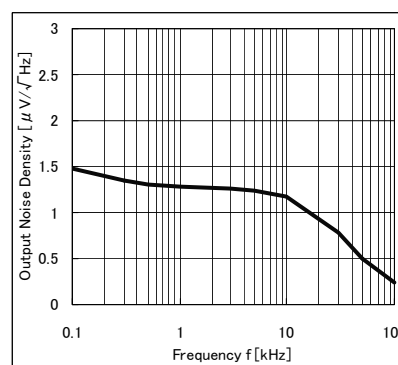


Fig.57 Noise - Freq.

●Reference data BH30SA3WGUT (Ta=25°C unless otherwise specified.)

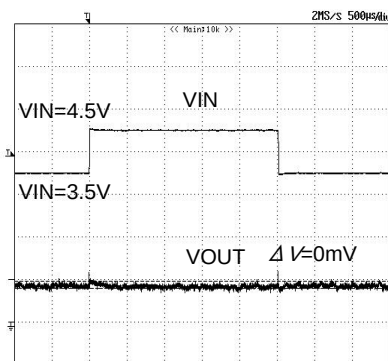


Fig.58 Transient_response
(Ta=-40°C)

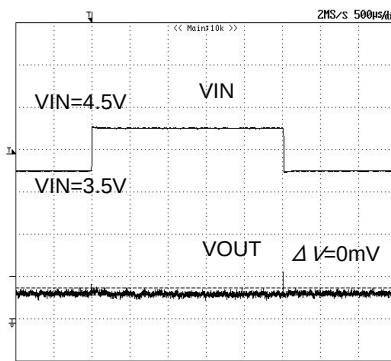


Fig.59 Transient_response
(Ta=25°C)

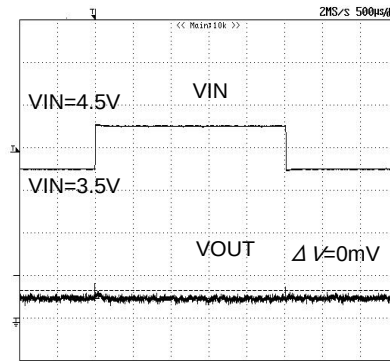


Fig.60 Transient_response
(Ta=85°C)

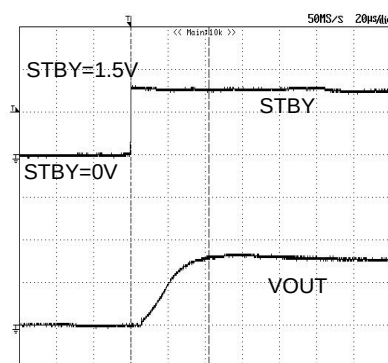


Fig.61 START_UP
(Ta=-40°C)

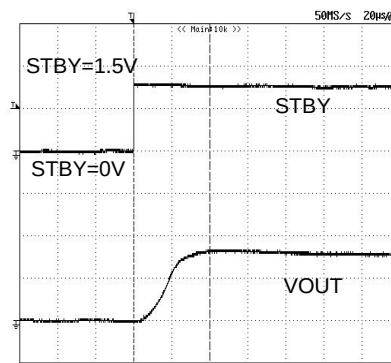


Fig.62 START_UP
(Ta=25°C)

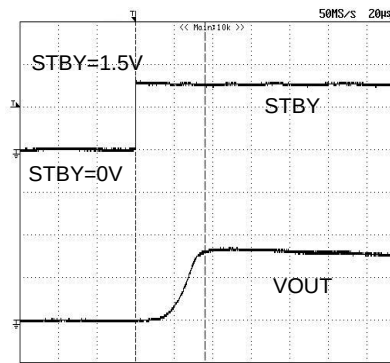


Fig.63 START_UP
(Ta=85°C)

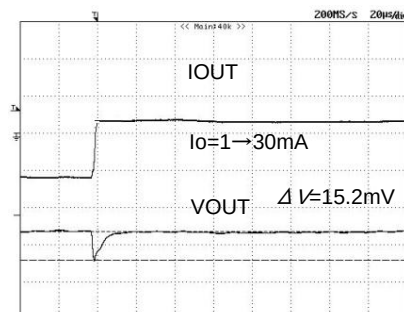


Fig.64 Load_response
(Ta=-40°C)
(Io=1→30mA)

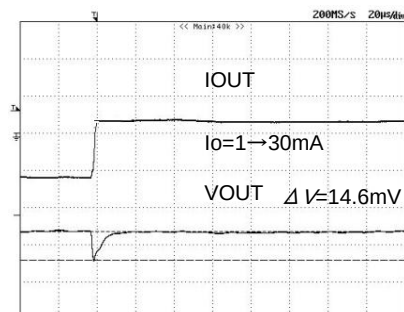


Fig.65 Load_response
(Ta=25°C)
(Io=1→30mA)

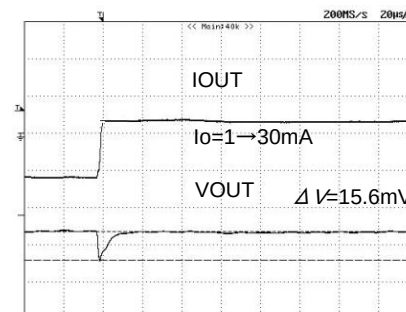


Fig.66 Load_response
(Ta=85°C)
(Io=1→30mA)

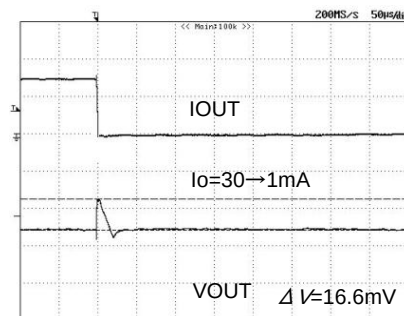


Fig.67 Load_response
(Ta=-40°C)
(Io=30→1mA)

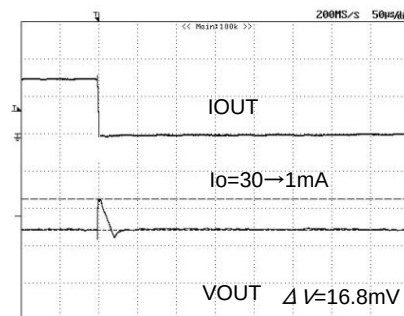


Fig.68 Load_response
(Ta=25°C)
(Io=30→1mA)

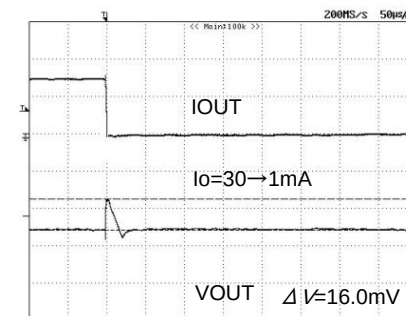
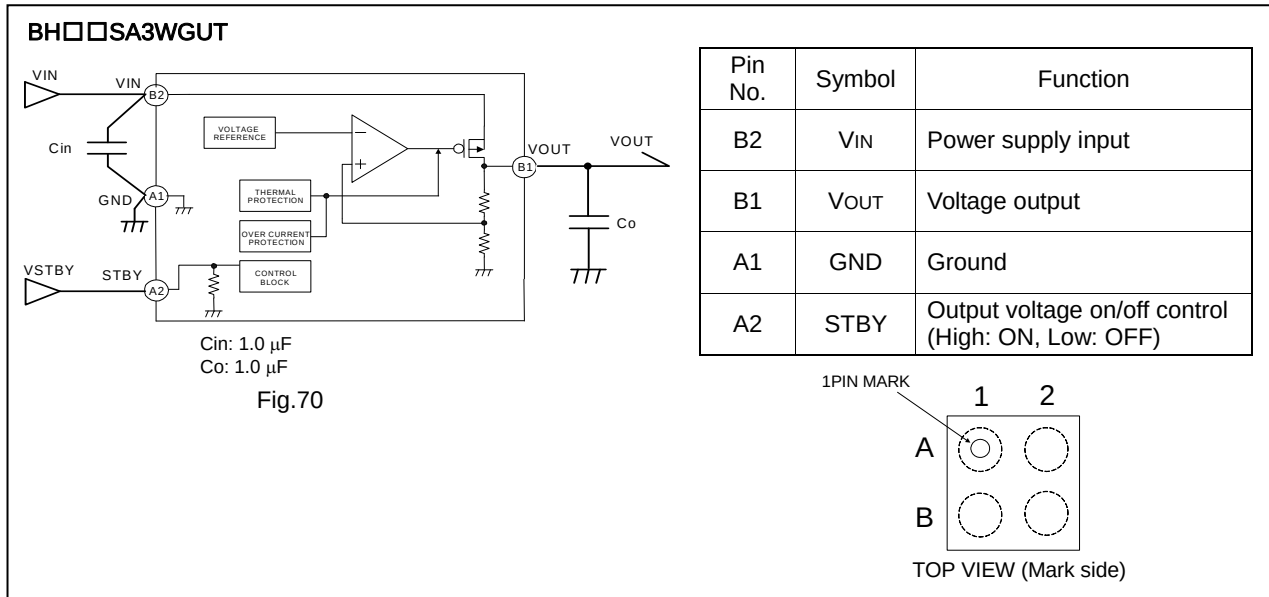


Fig.69 Load_response
(Ta=85°C)
(Io=30→1mA)

●Block Diagram, Recommended Circuit Diagram, and Pin Assignment Diagram



●Power Dissipation (Pd)

1. Power dissipation (Pd)

Power dissipation calculations include estimates of power dissipation characteristics and internal IC power consumption and should be treated as rough guidelines. In the event that the IC is used in an environment where this power dissipation is exceeded, the attendant rise in the chip's temperature will trigger the thermal shutdown circuit, reducing the current capacity and otherwise degrading the IC's design performance. Allow for sufficient margins so that this power dissipation is not exceeded during IC operation.

Calculating the maximum internal IC power consumption (P_{MAX})

$$P_{MAX} = (V_{IN} - V_{OUT}) \times I_{OUT} (MAX.)$$

V_{IN}: Input voltage
V_{OUT}: Output voltage
I_{OUT} (MAX): Output current

2. Power dissipation/power dissipation reduction (Pd)

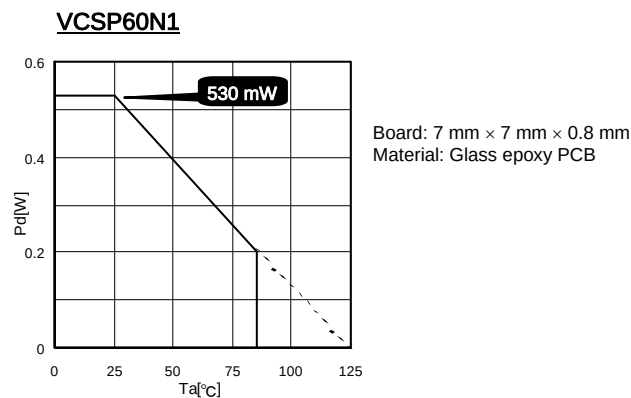


Fig.71 VCSP60N1 Power Dissipation/Power Dissipation Reduction (Example)

*Circuit design should allow a sufficient margin for the temperature range so that P_{MAX} < Pd.

●Input Output Capacitors

It is recommended to insert bypass capacitors between input and GND pins, positioning them as close to the pins as possible. These capacitors will be used when the power supply impedance increases or when long wiring routes are used, so they should be checked once the IC has been mounted.

Ceramic capacitors generally have temperature and DC bias characteristics. When selecting ceramic capacitors, use X5R or X7R or better models that offer good temperature and DC bias characteristics and high tolerant voltages.

Typical ceramic capacitor characteristics

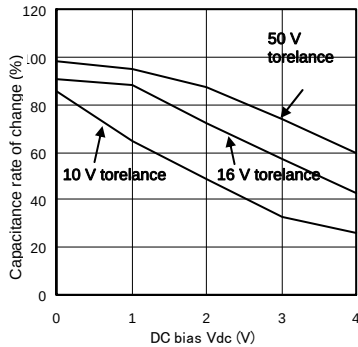


Fig.72 Capacitance vs Bias (Y5V)

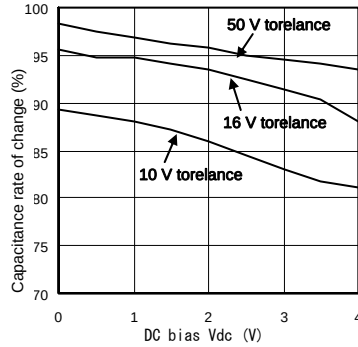


Fig.73 Capacitance vs Bias (X5R, X7R)

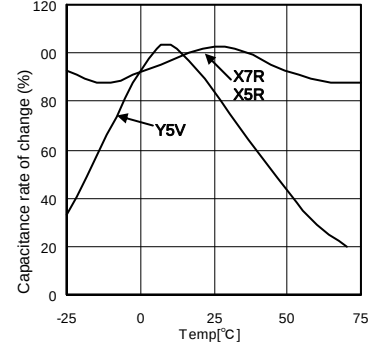


Fig.74 Capacitance vs Temperature (X5R, X7R, Y5V)

●Output Capacitors

Ceramic capacitors for stopping oscillation must be inserted between output and GND pins, positioned as close to the pins as possible. Larger output capacitance values provide greater stability as well as improved output load variation and other characteristics.

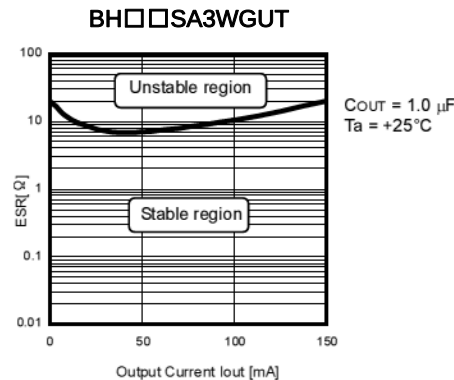


Fig.75 Stable Operating Region Characteristics (Example)

●Other Precautions

- Absolute maximum ratings
This product is subject to a strict quality management regime during its manufacture. However, damage may result if absolute maximum ratings such as applied voltage and operating temperature range are exceeded. Assumptions should not be made regarding the state of the IC (short mode or open mode) when such damage is suffered. A physical safety measure such as a fuse should be implemented when use of the IC in a special mode where the absolute maximum ratings may be exceeded is anticipated.
- Setting of heat
Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.
- Pin short and mistake fitting
Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC. Shorts between output pins or between output pins and the power supply and GND pins caused by the presence of a foreign object may result in damage to the IC.
- Thermal shutdown circuit (TSD)
The IC incorporates a built-in thermal shutdown circuit. The thermal shutdown circuit is designed only to shut the IC off to prevent runaway thermal operation. It is not designed to protect the IC or guarantee its operation. Do not continue to use the IC after operating this circuit or use the IC in an environment where the operation of the thermal shutdown circuit is assumed.
- Overcurrent protection circuit
The IC incorporates a built-in overcurrent protection circuit that operates according to the output current capacity. This circuit serves to protect the IC from damage when the load is shorted. The protection circuits use fold-back type current limiting and are designed to limit current flow by not latching up in the event of a large and instantaneous current flow originating from a large capacitor or other component. These protection circuits are effective in preventing damage due to sudden and unexpected accidents. However, the IC should not be used in applications characterized by the continuous operation or transitioning of the protection circuits.
- Actions in strong magnetic fields
Use caution when using the IC in the presence of a strong magnetic field as such environments may occasionally cause the chip to malfunction.
- Mutual impedance
Power supply and ground wiring should reflect consideration of the need to lower common impedance and minimize ripple as much as possible (by making wiring as short and thick as possible or rejecting ripple by incorporating inductance and capacitance).
- influence of strong light
Exposure of the IC to strong light sources such as infrared light from a halogen lamp may cause the IC to malfunction. When it is necessary to use the IC in such environments, implement measures to block exposure to light from the light source. During testing, exposure to neither fluorescent lighting nor white LEDs had a significant effect on the IC.
- GND potential
Ensure a minimum GND pin potential in all operating conditions.
In addition, ensure that no pins other than the GND pin carry a voltage less than or equal to the GND pin, including during actual transient phenomena.

●Back Current

In applications where the IC may be exposed to back current flow, it is recommended to create a route to dissipate this current by inserting a bypass diode between the VIN and VOUT pins.

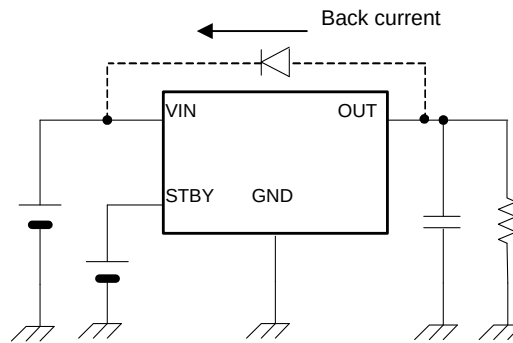


Fig.76 Example Bypass Diode Connection

●Testing on Application Boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process.

●Regarding Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements.

For example, when a resistor and transistor are connected to pins as shown in Fig.77

○The P/N junction functions as a parasitic diode when $GND > (Pin A)$ for the resistor or $GND > (Pin B)$ for the transistor (NPN).

○Similarly, when $GND > (Pin B)$ for the transistor (NPN), the parasitic diode described above combines with the N layer of other adjacent elements to operate as a parasitic NPN transistor.

The formation of parasitic elements as a result of the relationships of the potentials of different pins is an inevitable result of the IC's architecture. The operation of parasitic elements can cause interference with circuit operation as well as IC malfunction and damage. For these reasons, it is necessary to use caution so that the IC is not used in a way that will trigger the operation of parasitic elements, such as by the application of voltages lower than the GND (P substrate) voltage to input pins.

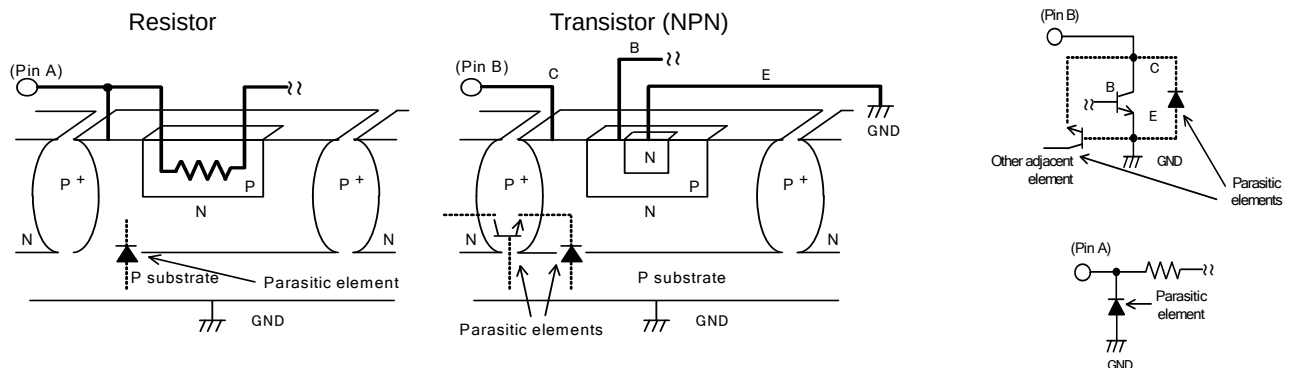
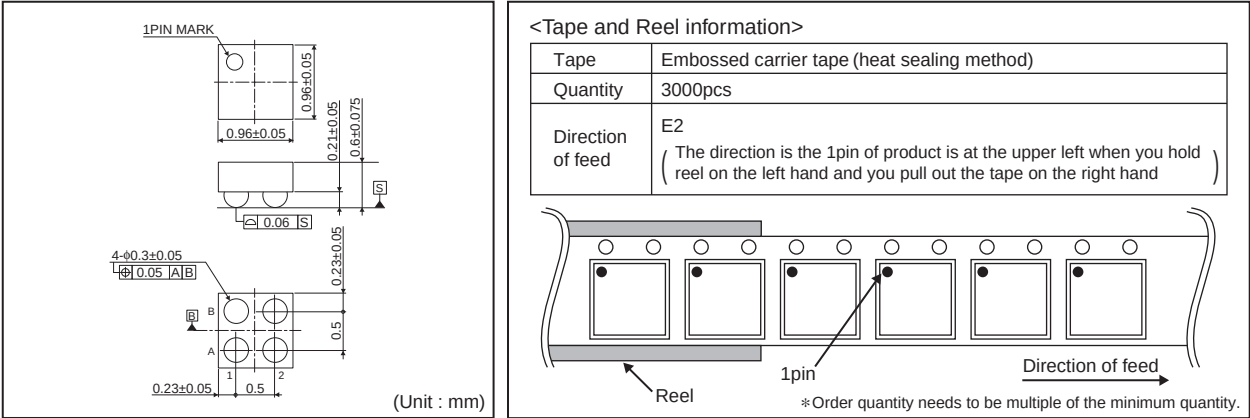


Fig.77

●Selecting a Model Name When Ordering

B	H	1	8	S	A	3	W	G	U	T	E	2
ROHM model name		Output voltage		Series Chip sizepackage		Shutdown switch		Packege GUT: VCSP60N1		Packaging and forming specification E2: Embossed tape and reel		

VCSP60L1(BHXXSA3WGUT)



Notice

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- Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment ^(Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

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 - Installation of redundant circuits to reduce the impact of single or multiple circuit failure
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 - Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - Sealing or coating our Products with resin or other coating materials
 - Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - Use of the Products in places subject to dew condensation
- The Products are not subject to radiation-proof design.
- Please verify and confirm characteristics of the final or mounted products in using the Products.
- In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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